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8Mb Ultra-Low Power Asynchronous CMOS SRAM

512K × 16bit

Overview

The N08L6182A is an integrated memory device containing a 8 Mbit Static Random Access Memory organized as 524,288 words by 16 bits. The device is designed and fabricated using ON Semiconductor's advanced CMOS technology to provide both high-speed performance and ultra-low power. The device operates with two chip enable (CE1 and CE2) controls and output enable (OE) to allow for easy memory expansion. Byte controls (UB and LB) allow the upper and lower bytes to be accessed independently and can also be used to deselect the device. The N08L6182A is optimal for various applications where low-power is critical such as battery backup and hand-held devices. The device can operate over a very wide temperature range of -40°C to +85°C and is available in JEDEC standard packages compatible with other standard 512Kb x 16 SRAMs.

Features

- **Single Wide Power Supply Range**
1.65 to 2.2 Volts
- **Very low standby current**
0.5µA at 1.8V (Typical)
- **Very low operating current**
1.0mA at 1.8V and 1µs (Typical)
- **Very low Page Mode operating current**
0.5mA at 1.8V and 1µs (Typical)
- **Simple memory control**
Dual Chip Enables (CE1 and CE2)
Byte control for independent byte operation
Output Enable (OE) for memory expansion
- **Low voltage data retention**
V_{CC} = 1.2V
- **Very fast output enable access time**
25ns OE access time
- **Very fast Page Mode access time**
t_{AAP} = 25ns
- **Automatic power down to standby mode**
- **TTL compatible three-state output driver**

Product Family

Part Number	Package Type	Operating Temperature	Power Supply (V _{CC})	Speed	Standby Current (I _{SB}), Typical	Operating Current (I _{CC}), Typical
N08L6182AB	48 - BGA	-40°C to +85°C	1.65V - 2.2V	70ns @ 1.8V	0.5 µA	1 mA @ 1MHz
N08L6182AB2	48 - BGA Green			85ns @ 1.65V		

Pin Configuration

	1	2	3	4	5	6
A	LB	OE	A ₀	A ₁	A ₂	CE2
B	I/O ₈	UB	A ₃	A ₄	CE1	I/O ₀
C	I/O ₉	I/O ₁₀	A ₅	A ₆	I/O ₁	I/O ₂
D	V _{SS}	I/O ₁₁	A ₁₇	A ₇	I/O ₃	V _{CC}
E	V _{CC}	I/O ₁₂	NC	A ₁₆	I/O ₄	V _{SS}
F	I/O ₁₄	I/O ₁₃	A ₁₄	A ₁₅	I/O ₅	I/O ₆
G	I/O ₁₅	NC	A ₁₂	A ₁₃	WE	I/O ₇
H	A ₁₈	A ₈	A ₉	A ₁₀	A ₁₁	NC

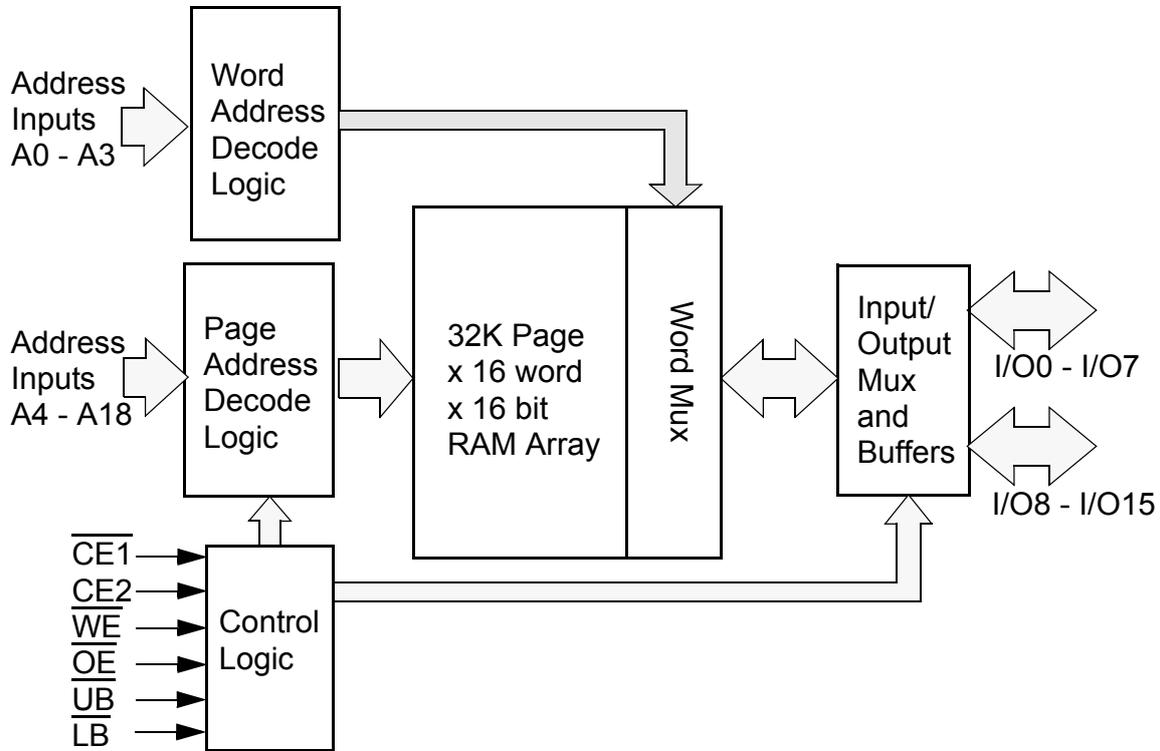
48 Pin BGA (top)
8 x 10 mm

Pin Descriptions

Pin Name	Pin Function
A ₀ -A ₁₈	Address Inputs
WE	Write Enable Input
CE1, CE2	Chip Enable Input
OE	Output Enable Input
LB	Lower Byte Enable Input
UB	Upper Byte Enable Input
I/O ₀ -I/O ₁₅	Data Inputs/Outputs
V _{CC}	Power
V _{SS}	Ground
NC	Not Connected

N08L6182A

Functional Block Diagram



Functional Description

$\overline{CE1}$	$CE2$	\overline{WE}	\overline{OE}	\overline{UB}	\overline{LB}	I/O ₀ - I/O ₁₅ ¹	MODE	POWER
H	X	X	X	X	X	High Z	Standby ²	Standby
X	L	X	X	X	X	High Z	Standby ²	Standby
X	X	X	X	H	H	High Z	Standby ²	Standby
L	H	L	X ³	L ¹	L ¹	Data In	Write ³	Active -> Standby ⁴
L	H	H	L	L ¹	L ¹	Data Out	Read	Active -> Standby ⁴
L	H	H	H	L ¹	L ¹	High Z	Active	Standby ⁴

1. When \overline{UB} and \overline{LB} are in select mode (low), I/O₀ - I/O₁₅ are affected as shown. When \overline{LB} only is in the select mode only I/O₈ - I/O₇ are affected as shown. When \overline{UB} is in the select mode only I/O₈ - I/O₁₅ are affected as shown.

2. When the device is in standby mode, control inputs (\overline{WE} , \overline{OE} , \overline{UB} , and \overline{LB}), address inputs and data input/outputs are internally isolated from any external influence and disabled from exerting any influence externally.

3. When \overline{WE} is invoked, the \overline{OE} input is internally disabled and has no effect on the circuit.

4. The device will consume active power in this mode whenever addresses are changed. Data inputs are internally isolated from any external influence.

Capacitance¹

Item	Symbol	Test Condition	Min	Max	Unit
Input Capacitance	C _{IN}	V _{IN} = 0V, f = 1 MHz, T _A = 25°C		8	pF
I/O Capacitance	C _{I/O}	V _{IN} = 0V, f = 1 MHz, T _A = 25°C		8	pF

1. These parameters are verified in device characterization and are not 100% tested

N08L6182A

Absolute Maximum Ratings¹

Item	Symbol	Rating	Unit
Voltage on any pin relative to V _{SS}	V _{IN,OUT}	-0.3 to V _{CC} +0.3	V
Voltage on V _{CC} Supply Relative to V _{SS}	V _{CC}	-0.3 to 3.0	V
Power Dissipation	P _D	500	mW
Storage Temperature	T _{STG}	-40 to 125	°C
Operating Temperature	T _A	-40 to +85	°C
Soldering Temperature and Time	T _{SOLDER}	260°C, 10sec	°C

1. Stresses greater than those listed above may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operating section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Operating Characteristics (Over Specified Temperature Range)

Item	Symbol	Test Conditions	Min.	Typ ¹	Max	Unit
Supply Voltage	V _{CC}		1.65	1.8	2.2	V
Data Retention Voltage	V _{DR}	Chip Disabled ³	1.2			V
Input High Voltage	V _{IH}		0.7V _{CC}		V _{CC} +0.3	V
Input Low Voltage	V _{IL}		-0.3		0.3V _{CC}	V
Output High Voltage	V _{OH}	I _{OH} = 0.2mA	V _{CC} -0.2			V
Output Low Voltage	V _{OL}	I _{OL} = -0.2mA			0.2	V
Input Leakage Current	I _{LI}	V _{IN} = 0 to V _{CC}			0.5	μA
Output Leakage Current	I _{LO}	\overline{OE} = V _{IH} or Chip Disabled			0.5	μA
Read/Write Operating Supply Current @ 1 μs Cycle Time ²	I _{CC1}	V _{CC} =2.2 V, V _{IN} =V _{IH} or V _{IL} Chip Enabled, I _{OUT} = 0		1.0	3.0	mA
Read/Write Operating Supply Current @ 70 ns Cycle Time ²	I _{CC2}	V _{CC} =2.2 V, V _{IN} =V _{IH} or V _{IL} Chip Enabled, I _{OUT} = 0		10.0	14.0	mA
Page Mode Operating Supply Current @ 70 ns Cycle Time ²	I _{CC3}	V _{CC} =2.2 V, V _{IN} =V _{IH} or V _{IL} Chip Enabled, I _{OUT} = 0		0.5	3.0	mA
Read/Write Quiescent Operating Supply Current ³	I _{CC4}	V _{CC} =2.2 V, V _{IN} =V _{IH} or V _{IL} Chip Enabled, I _{OUT} = 0, f = 0			20	μA
Maximum Standby Current ³	I _{SB1}	V _{IN} = V _{CC} or 0V Chip Disabled t _A = 85°C, V _{CC} = 2.2 V		0.5	20.0	μA
Maximum Data Retention Current ³	I _{DR}	V _{CC} = 1.2V, V _{IN} = V _{CC} or 0 Chip Disabled, t _A = 85°C			10	μA

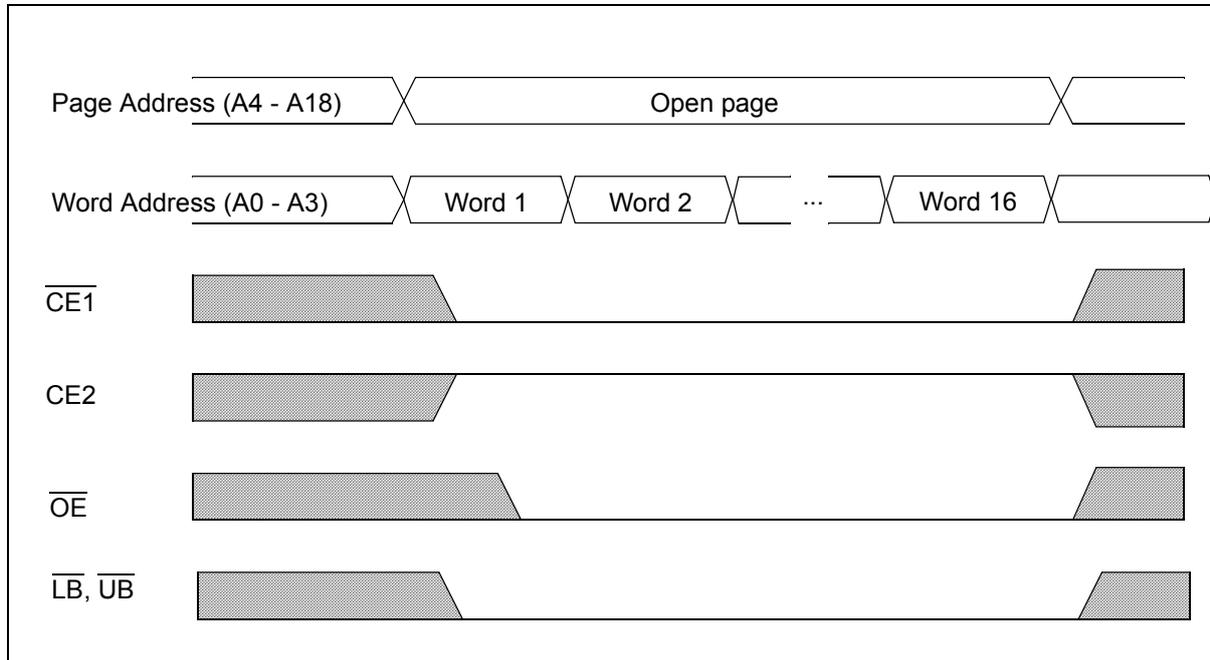
1. Typical values are measured at V_{CC}=V_{CC} Typ., T_A=25°C and not 100% tested.

2. This parameter is specified with the outputs disabled to avoid external loading effects. The user must add current required to drive output capacitance expected in the actual system.

3. This device assumes a standby mode if the chip is disabled ($\overline{CE1}$ high or CE2 low). In order to achieve low standby current all inputs must be within 0.2 volts of either V_{CC} or V_{SS}.

N08L6182A

Power Savings with Page Mode Operation ($\overline{WE} = V_{IH}$)



Note: Page mode operation is a method of addressing the SRAM to save operating current. The internal organization of the SRAM is optimized to allow this unique operating mode to be used as a valuable power saving feature.

The only thing that needs to be done is to address the SRAM in a manner that the internal page is left open and 16-bit words of data are read from the open page. By treating addresses A0-A3 as the least significant bits and addressing the 16 words within the open page, power is reduced to the page mode value which is considerably lower than standard operating currents for low power SRAMs.

N08L6182A

Timing Test Conditions

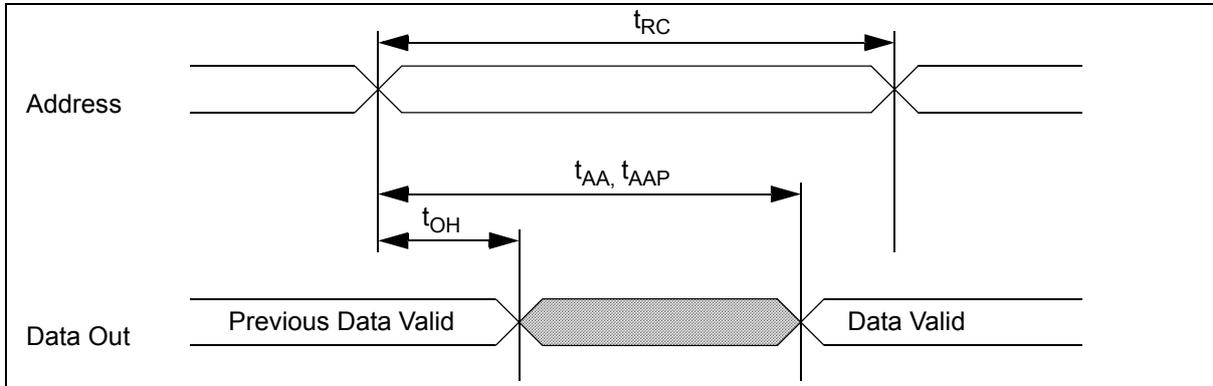
Item	
Input Pulse Level	0.1V _{CC} to 0.9 V _{CC}
Input Rise and Fall Time	5ns
Input and Output Timing Reference Levels	0.5 V _{CC}
Output Load	30pF
Operating Temperature	-40 to +85 °C

Timing

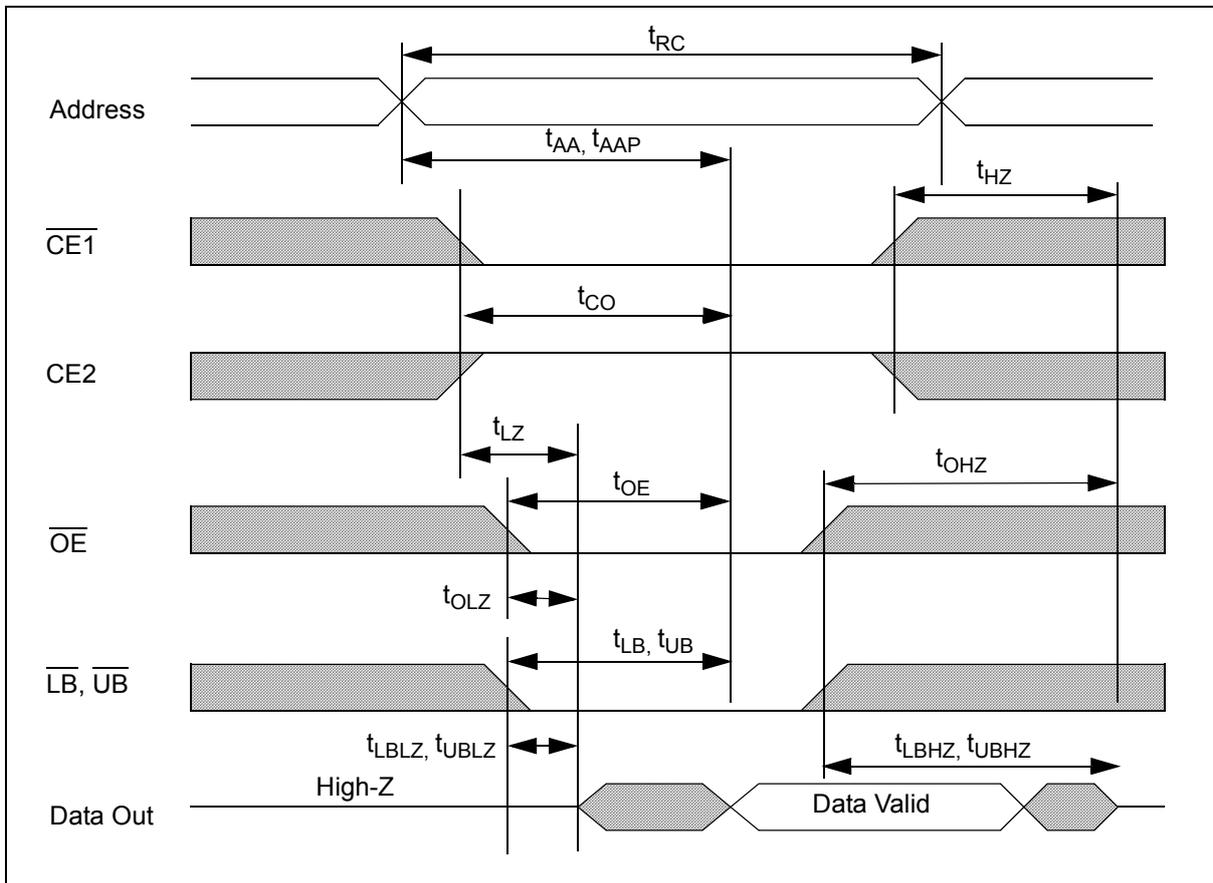
Item	Symbol	1.65 - 2.2 V		1.8 - 2.2 V		Units
		Min.	Max.	Min.	Max.	
Read Cycle Time	t _{RC}	85		70		ns
Address Access Time (Random Access)	t _{AA}		85		70	ns
Address Access Time (Page Mode)	t _{AAP}		30		25	ns
Chip Enable to Valid Output	t _{CO}		85		70	ns
Output Enable to Valid Output	t _{OE}		30		25	ns
Byte Select to Valid Output	t _{LB} , t _{UB}		85		70	ns
Chip Enable to Low-Z output	t _{LZ}	10		10		ns
Output Enable to Low-Z Output	t _{OLZ}	5		5		ns
Byte Select to Low-Z Output	t _{LBZ} , t _{UBZ}	10		10		ns
Chip Disable to High-Z Output	t _{HZ}	0	20	0	20	ns
Output Disable to High-Z Output	t _{OHZ}	0	20	0	20	ns
Byte Select Disable to High-Z Output	t _{LBHZ} , t _{UBHZ}	0	20	0	20	ns
Output Hold from Address Change	t _{OH}	5		5		ns
Write Cycle Time	t _{WC}	85		70		ns
Chip Enable to End of Write	t _{CW}	50		50		ns
Address Valid to End of Write	t _{AW}	50		50		ns
Byte Select to End of Write	t _{LBW} , t _{UBW}	50		50		ns
Write Pulse Width	t _{WP}	40		40		ns
Address Setup Time	t _{AS}	0		0		ns
Write Recovery Time	t _{WR}	0		0		ns
Write to High-Z Output	t _{WHZ}		20		20	ns
Data to Write Time Overlap	t _{DW}	40		40		ns
Data Hold from Write Time	t _{DH}	0		0		ns
End Write to Low-Z Output	t _{OW}	5		5		ns

N08L6182A

Timing of Read Cycle ($\overline{CE1} = \overline{OE} = V_{IL}, \overline{WE} = CE2 = V_{IH}$)

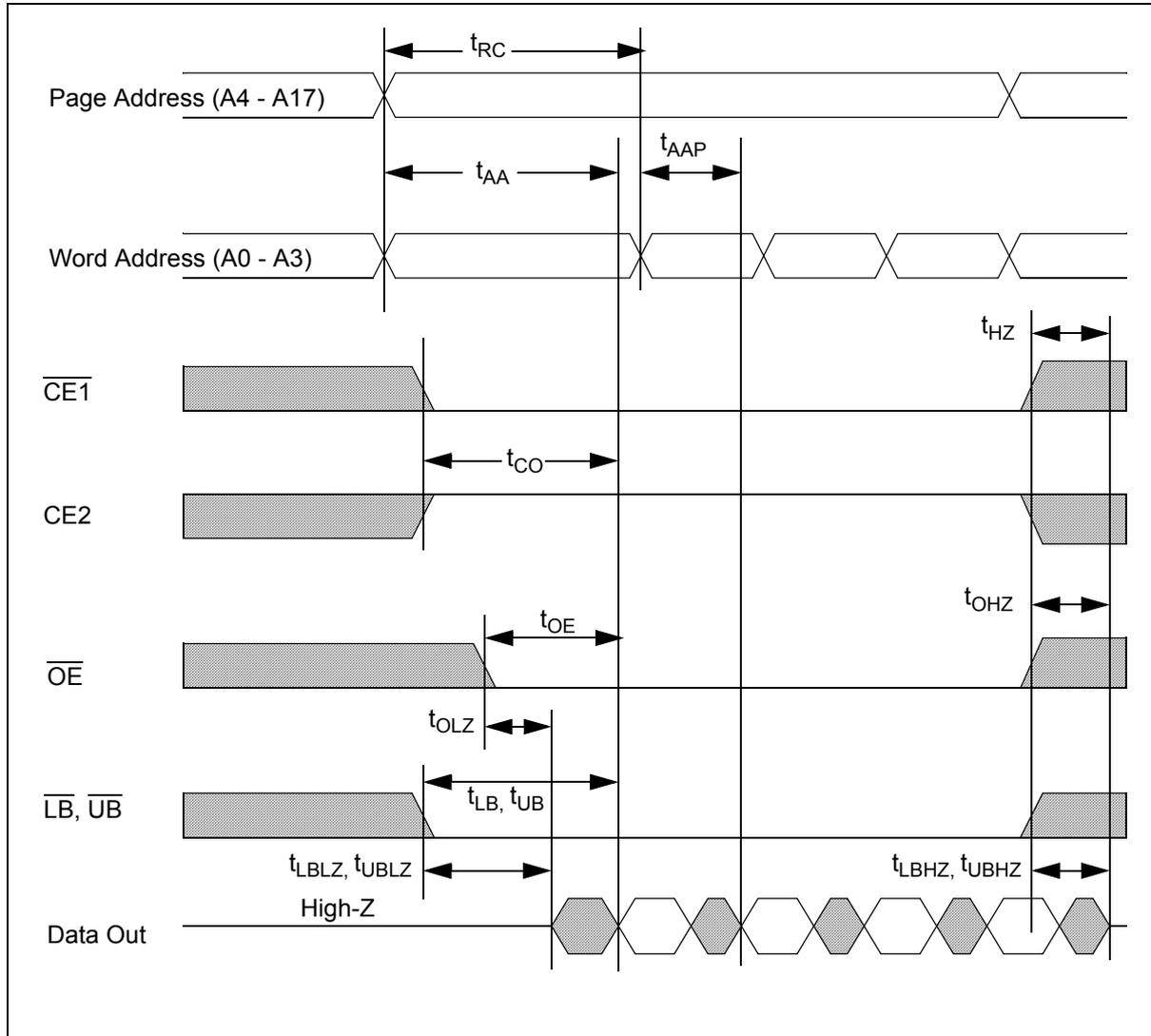


Timing Waveform of Read Cycle ($\overline{WE} = V_{IH}$)



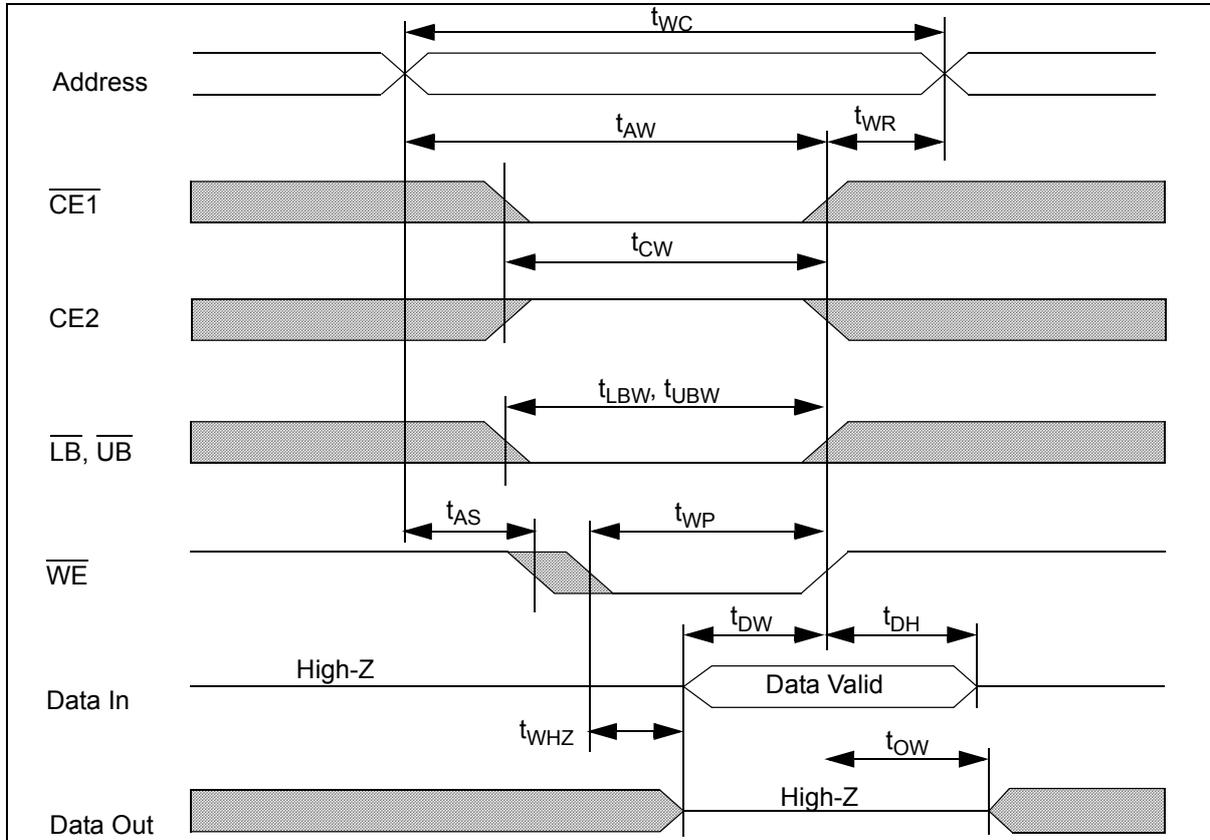
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Timing Waveform of Page Mode Read Cycle ($\overline{WE} = V_{IH}$)

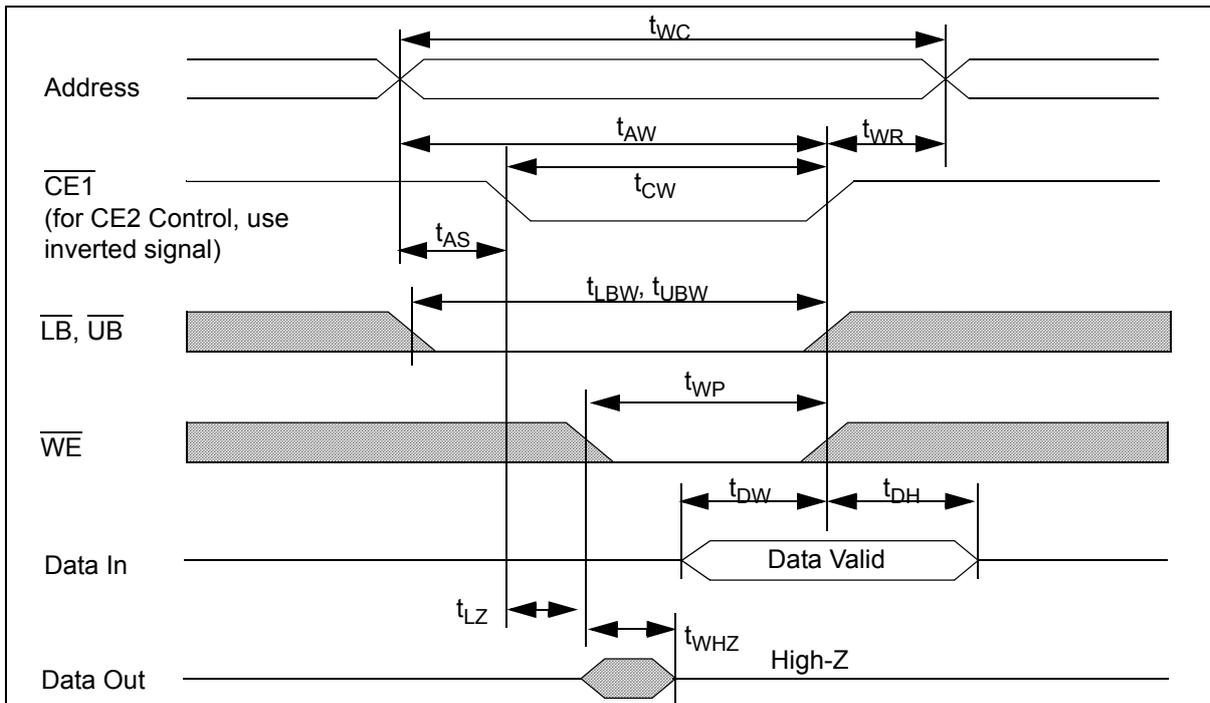


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Timing Waveform of Write Cycle ($\overline{\text{WE}}$ control)

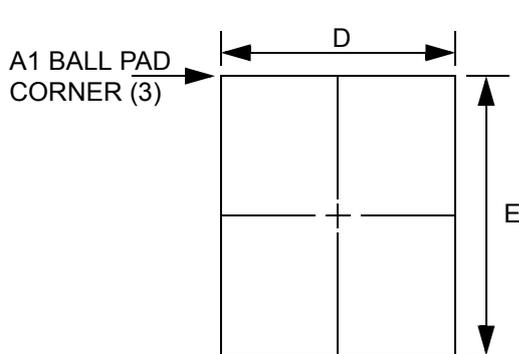


Timing Waveform of Write Cycle ($\overline{\text{CE1}}$ Control)

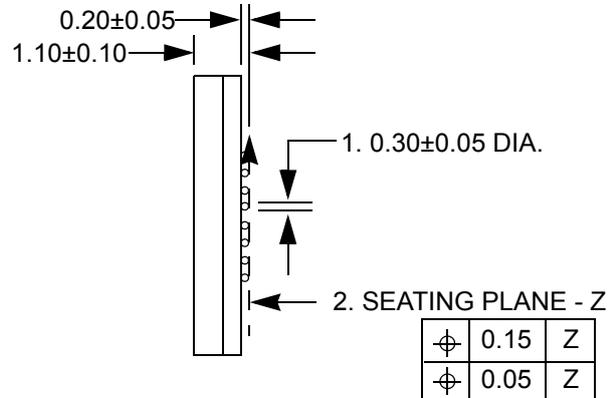


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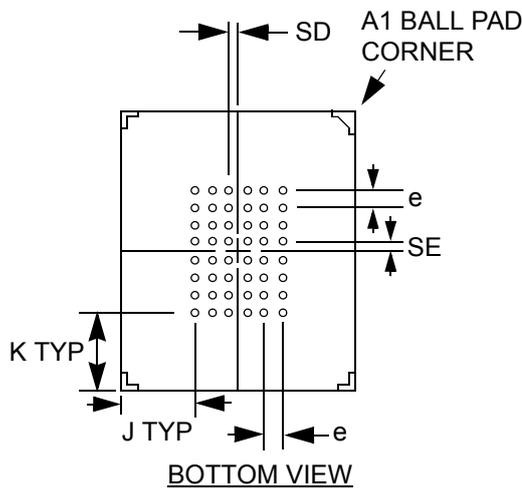
Ball Grid Array Package



TOP VIEW



SIDE VIEW



BOTTOM VIEW

1. DIMENSION IS MEASURED AT THE MAXIMUM SOLDER BALL DIAMETER. PARALLEL TO PRIMARY Z.

2. PRIMARY DATUM Z AND SEATING PLANE ARE DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.

3. A1 BALL PAD CORNER I.D. TO BE MARKED BY INK.

Dimensions (mm)

D	E	e = 0.75				BALL MATRIX TYPE
		SD	SE	J	K	
8±0.10	10±0.10	0.375	0.375	2.125	2.375	FULL

N08L6182A

Ordering Information

Part Number	Package	Shipping Method
N08L6182AB7I	Leaded 48-BGA	Tray
N08L6182AB27I	Green 48-BGA (RoHS Compliant)	Tray
N08L6182AB7IT	Leaded 48-BGA	Tape & Reel
N08L6182AB27IT	Green 48-BGA (RoHS Compliant)	Tape & Reel

Revision History

Revision	Date	Change Description
A	Jan. 2001	Initial Advance Release
B	Mar. 2001	Corrected voltage in Timing table
C	Dec. 2001	Part number change from EM512W16, modified Overview and Features, added Page Mode Operatin diagram, revised Operating Characteristics table, Package diagram, Functional Description table and Ordering Information diagram
D	Nov. 2002	Replaced Isb and Icc on Product Family table with typical values
E	Oct. 2004	Added Green Package Option
F	Dec. 2005	Added RoHS compliant on green packages
G	September 2006	Converted to AMI Semiconductor
8	July 2008	Converted to ON Semiconductor and new part numbers

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